

Smart Low-Side Switch

Features

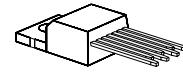
- Power limitation
- Thermal shutdown
- Overload protection
- Short circuit protection
- Diagnostic feedback
- Overvoltage protection
- Reverse polarity protection
- µC compatible input
- Electrostatic discharge (ESD) protection

Product Summary

Supply voltage	V_S	6.5 - 45	V
Drain source voltage	$V_{DS(AZ)max}$	65	V
On resistance	$R_{ON(typ)}$	0.25	Ω
Output current	I_D	4	A



P - TO220 - 7-1



P - TO220 - 7-2

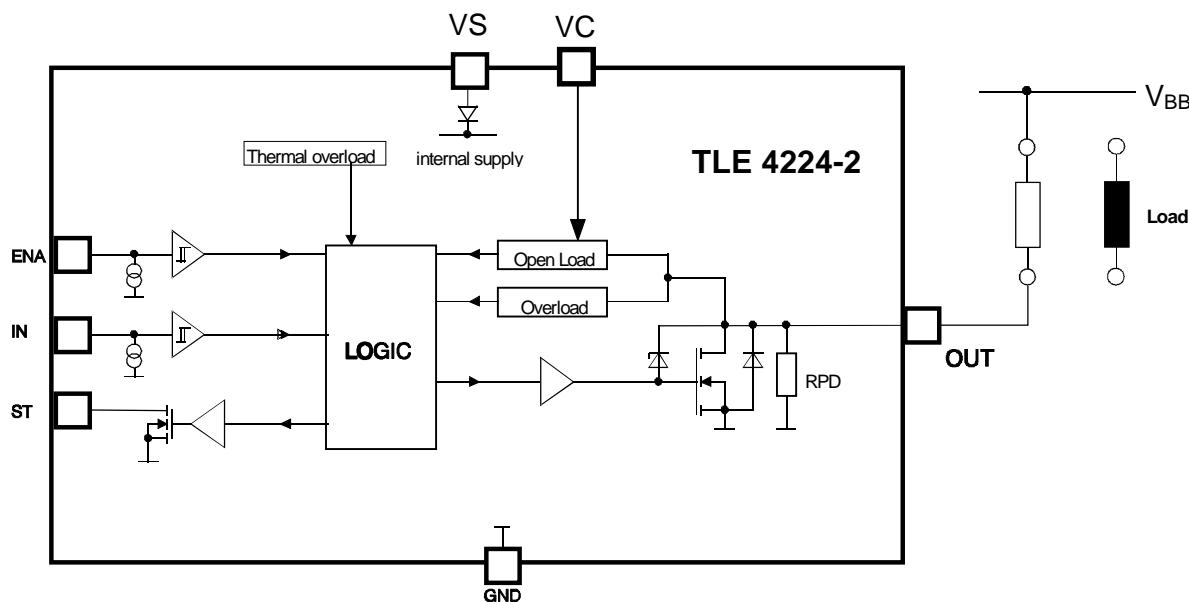
Application

- All kinds of resistive and inductive loads (relays,electromagnetic valves)
- µC compatible power switch for 12 and 24 V applications
- Solenoid control switch in automotive and industrial control systems

General description

Single channel Low-Side Switch in Smart Power Technology (SPT) with µC compatible input and an open drain DMOS output stage. The TLE 4224-2 is fully protected by embedded protection functions and designed for automotive and industrial applications.

Block Diagram

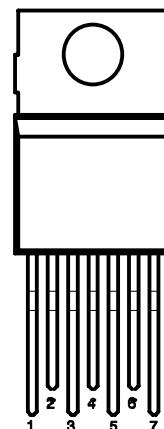


Maximum Ratings for $T_j = -40^\circ\text{C}$ to 150°C

Parameter	Symbol	Values	Unit
Supply voltage	V_S	- 15 ... + 60	V
Supply voltage operational range	V_S	+ 5.5 ... + 45	V
Compare voltage	V_C	- 0.3 ... 65	V
Continuous drain source voltage (OUT)	V_{DS}	45	V
Input voltage (IN)	V_{IN}	- 0.3 ... + 6	V
Status output voltage (ST)	V_{ST}	- 0.3 ... + 32	V
Operating temperature range	T_j	- 40 ... + 150	$^\circ\text{C}$
Storage temperature range	T_{stg}	- 55 ... + 150	
Output current	$I_{D(\text{lim})}$	self limited	A
Status output current	I_{ST}	- 5 ... + 5	mA
Inductive load switch off dissipation energy $T_{\text{case}} = 125^\circ\text{C}$	E_{AS}	100	mJ
$T_{\text{case}} = 75^\circ\text{C}$		200	
Thermal resistance junction - case	R_{thJC}	3	K/W
junction - ambient	R_{thJA}	65	

Pin Definitions and Functions**Pin Configuration**

Pin	Symbol	Function
1	ST	Status Output (open drain) for error monitoring
2	IN	Control Input, active high
3	ENA	Enable Input, active high
4	GND	Ground, connected internally to cooling lug
5	VC	Compare voltage for open load detection
6	OUT	Power Output (open drain)
7	VS	Supply Voltage



Electrical Characteristics

Parameter and Conditions $V_S = 6.5 \text{ to } 45 \text{ V}$; $T_j = -40 \text{ }^\circ\text{C} \text{ to } +150 \text{ }^\circ\text{C}$ (unless otherwise specified)	Symbol	Values			Unit
		min	typ	max	

1. Power Supply (V_S)

Supply current (Output ON)	I_S			5	mA
Supply current (Output OFF) $V_S \leq 18 \text{ V}$	I_S			1.5	mA
Operation voltage	V_S	5.5		45	V

2. Power Outputs

ON state resistance; $I_D = 4 \text{ A}$	$T_j = 25 \text{ }^\circ\text{C}$ $T_j = 150 \text{ }^\circ\text{C}$	$R_{DS(ON)}$		0.25	0.5	Ω
Z-Diode clamping voltage (OUT)		$V_{DS(AZ)}$	45		65	V
Pull down resistor	$T_j = 25 \text{ }^\circ\text{C}$	R_{PD}	14	20	26	$\text{k}\Omega$
Output on delay time ¹	$I_D = 0.2 \text{ A}$	t_{on}	10	25	40	μs
Output off delay time ¹	$I_D = 2 \text{ A}$	t_{off}		50		
Output on fall time ¹	$I_D = 0.2 \text{ A}$	t_{fall}		20		
Output off rise time ¹	$I_D = 2 \text{ A}$	t_{rise}		25		
Output off status delay time ¹	$I_D = 2 \text{ A}$	t_4	20	40	60	
Output on status delay time ^{1,2}		t_5			50	
Overload switch-off delay time ³		t_{DSO}	50		150	

3. Digital Inputs (IN, ENA)

Input low voltage	V_{INL}	- 0.3		1.0	V
Input high voltage	V_{INH}	2.0		6.0	V
Input voltage hysteresis	V_{INHys}	0.2		0.6	V
Input pull down current $V_S \geq 9 \text{ V}; V_{IN} = 5 \text{ V}$	I_{IN}	50	100	140	μA
Enable pull down current $V_S \geq 9 \text{ V}; V_{ENA} = 5 \text{ V}$	I_{ENA}	5	15	22	μA

4. Digital Status Outputs (ST) open Drain

Output voltage low $I_{ST} = 2 \text{ mA}$	V_{STL}			0.5	V
Leakage current high	I_{STH}			10	μA

¹ See timing diagram, resistive load condition; $V_S \geq 9 \text{ V}$

² Time till status valid after switching on or error detection

³ This parameter will not be tested but assured by design

Electrical Characteristics

Parameter and Conditions $V_S = 6.5 \text{ to } 45 \text{ V}$; $T_j = -40 \text{ }^\circ\text{C} \text{ to } +150 \text{ }^\circ\text{C}$ (unless otherwise specified)	Symbol	Values			Unit
		min	typ	max	

5. Diagnostic Functions

Open load detection voltage $V_C = 0 \text{ V}$; $8 \leq V_S \leq 18 \text{ V}$ (Output OFF) $6.5 \leq V_S \leq 45 \text{ V}$	$V_{DS(OL)}$	$0.5*V_S$ $0.45*V_S$		$0.6*V_S$ $0.65*V_S$	V
Open load compare detection $6.5 \leq V_C \leq 18 \text{ V}$	$V_{DS(OL)C}$	$V_C - 1.6$		$V_C - 0.9$	V
Open load detection current (Output ON)	$I_{D(OL)}$	100		500	mA
Overload threshold current $T_j = 25^\circ\text{C}$ $V_S \geq 9.5 \text{ V}$ $T_j = 150^\circ\text{C}$	$I_{D(lim)}$	5.25 4			A
Overtemperature shutdown threshold ⁴	T_{th}	155		185	$^\circ\text{C}$
Hysteresis	T_{hys}		10		K
V_C -Input current $V_C \leq 18 \text{ V}$	I_{VC}			0.25	mA

Application Description

This IC is specially designed to drive inductive loads (relays, electromagnetic valves). An integrated clamp-diode limits the output voltage when inductive loads are discharged.

For the detection of errors there is a open-drain status output, which monitors the following errors by logic level:

- overloading of output (also shorted load to supply) in active mode
- open and shorted load to ground in active and inactive mode
- thermal overload.

Circuit Description

Input Circuits

The control and enable inputs, all active high, consist of schmitt triggers with hysteresis. All inputs are connected with pull-down current sources. Not connected inputs are interpreted as LOW.

Switching Stages

The power output consists of a DMOS-power transistor with open drain. The output stage is shorted load protected throughout the operating range. The integrated clamp-diode limit voltage spikes produced when inductive loads are discharged.

⁴ This parameter will not be tested but assured by design

Protective Circuits

An integrated diode protects the device against reverse polarity of the operating voltage. The load circuit withstands reverse poling within the limits of the maximum ratings (no shorted load permissible at the same time). The outputs are protected against current overload and thermal overload.

Error Detection

The status output signals the switching state at normal operating conditions (LOW = off; HIGH = on) and in case of errors. The outputs are set according to the diagnostic table below.

If current overload occurs, the error condition is stored into an internal register and the output is shutdown. To reset the register, the control input of the corresponding channel has to be switched off and then on again.

Open load is detected in on- and off-modus: In on-modus the load current is monitored , in the off-modus the ouput voltage is monitored.

The open load voltage threshold is programmable via the voltage supplied to the VC.

The state of the error detection circuit is directly dependent on the input status.

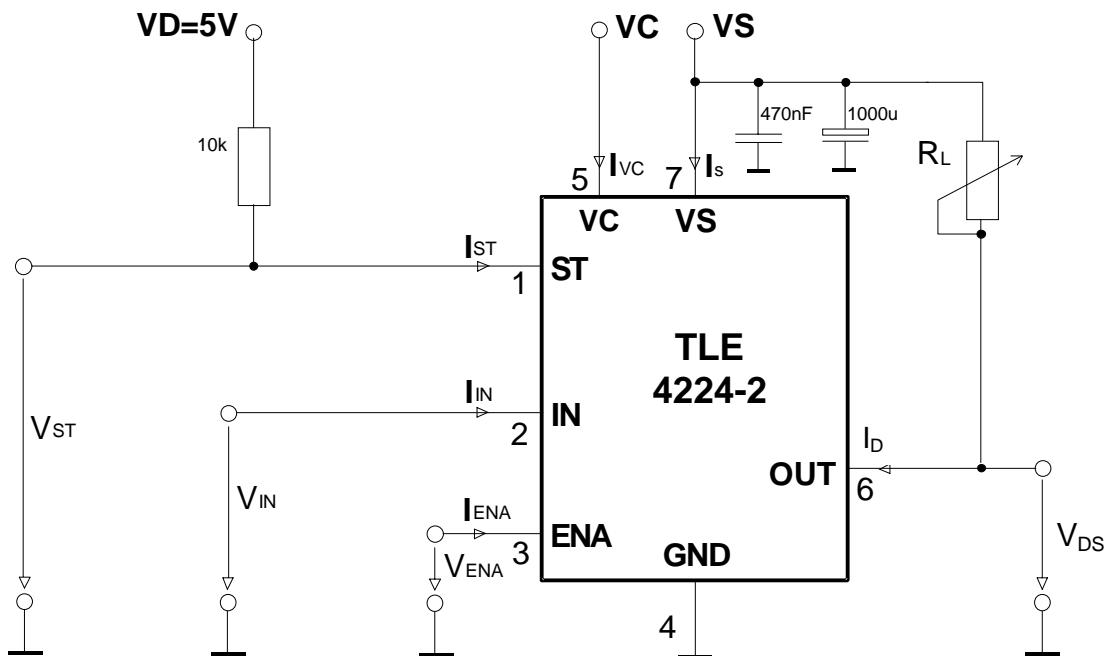
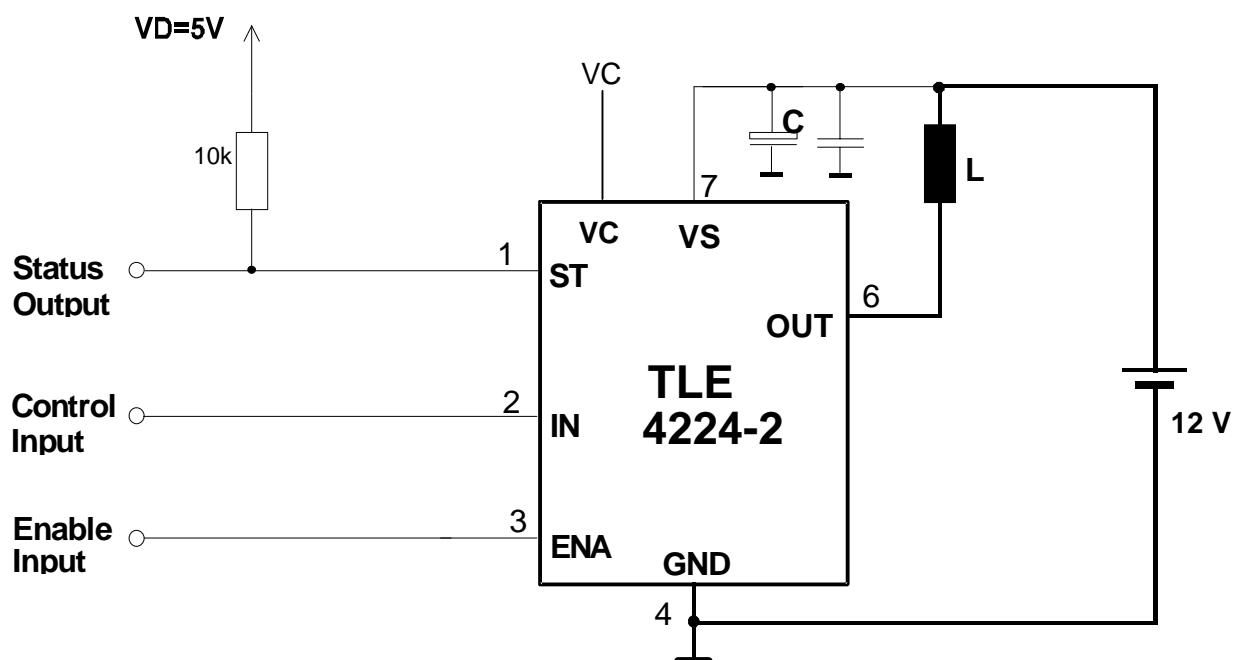
Diagnostic Table

Operating Condition	Enable Input	Control Input	Power Output	Status Output
	ENA	IN	OUT	ST
Normal Operation	L	L	OFF	L
	L	H	OFF	L
	H	L	OFF	L
	H	H	ON	H
Thermal Overload	X	L	OFF	H
	X	H	OFF	L
Open Load or shorted load to ground	L	L	OFF	H
	L	H	OFF	H
	H	L	OFF	H
	H	H	ON	L
Overload or shorted load to supply	L	L	OFF	L
	L	H	OFF	L
	H	L	OFF	L
	H	H	OFF	L

L = LOW

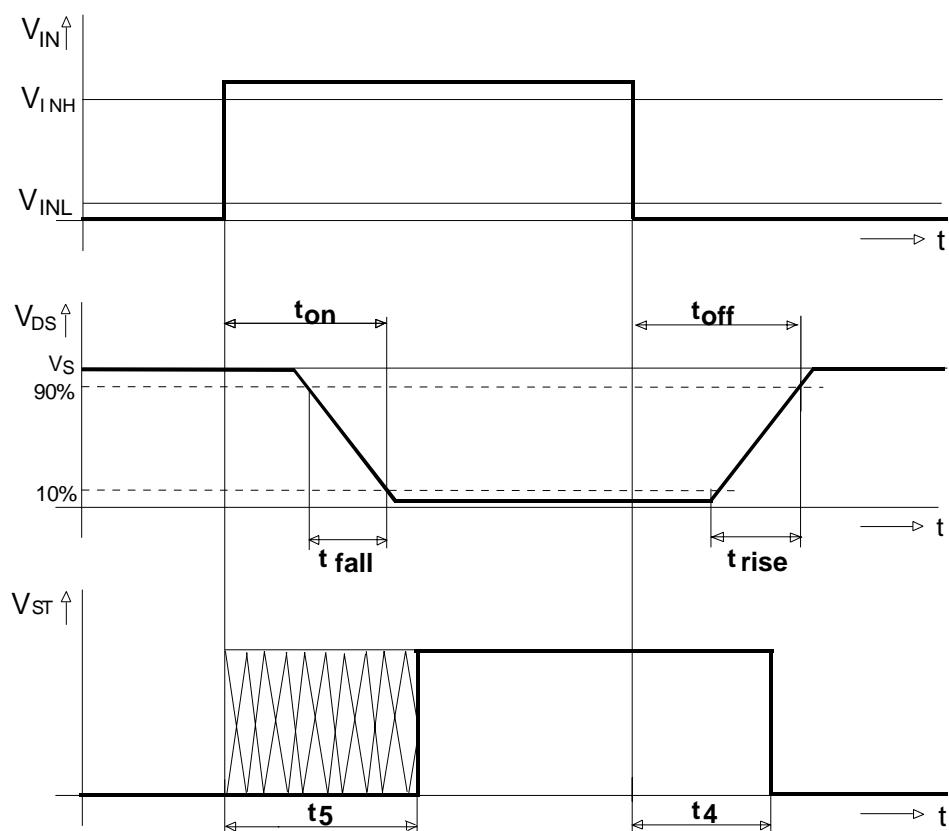
H = HIGH

X = RANDOM

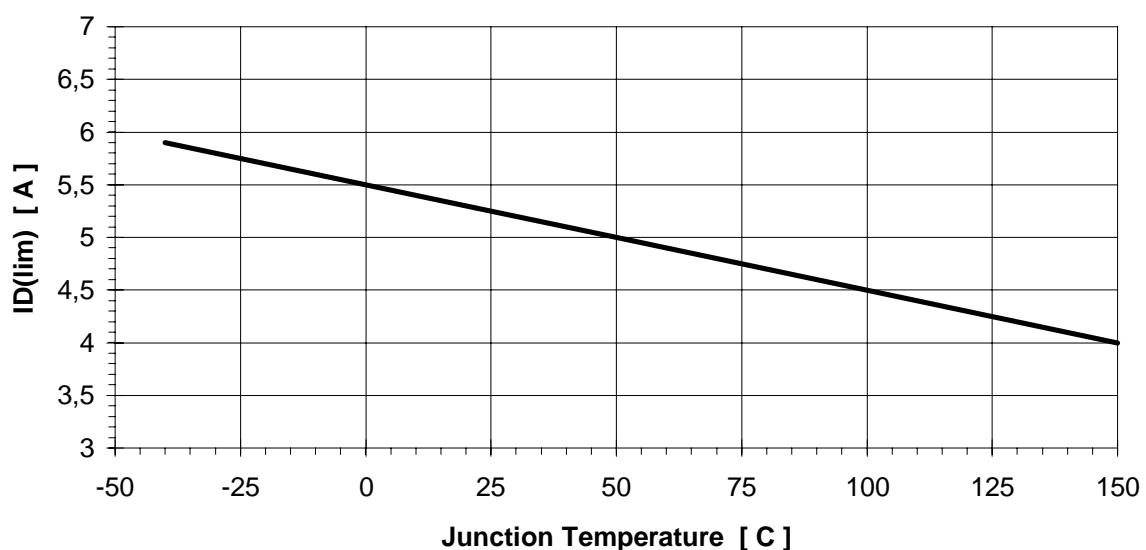
Test CircuitApplication Circuit

The blocking capacitor C is recommended to avoid critical negative voltage spikes on Vs in case of battery interruption during OFF-commutating.

Timing Diagram



Overload Current versus temperature



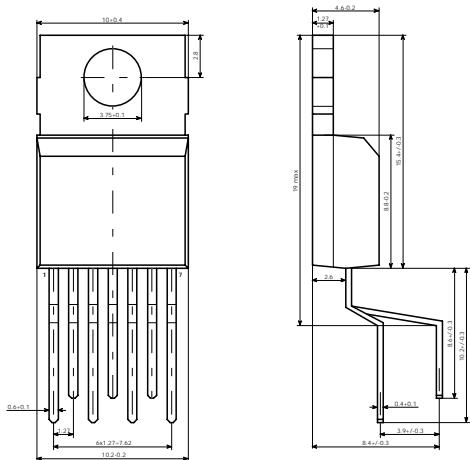
Package and ordering code

all dimensions in mm

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Ordering code

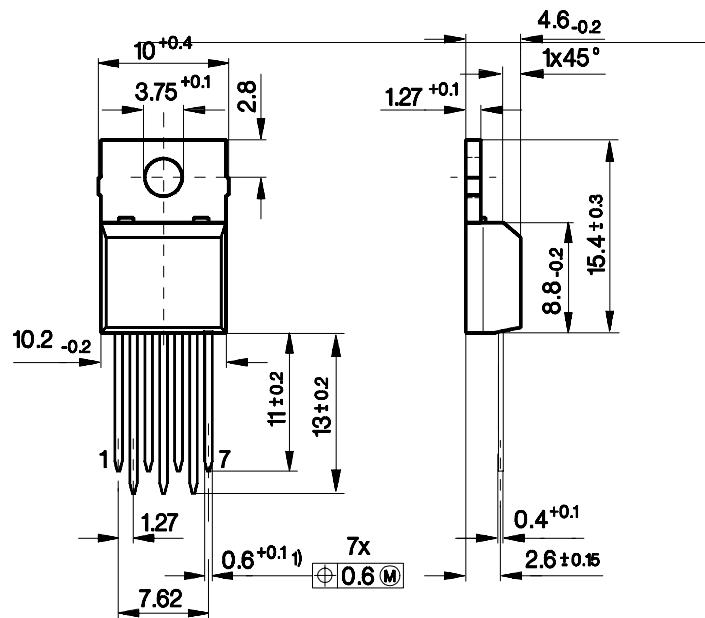
Q67000-A9062



P - TO220 - 7-2

Ordering code

Q67000-A9279



1) 0.75 - 0.15 at dam bar (max. 1.8 from body)

1) 0.75 - 0.15 im Dichtstegbereich (max. 1.8 vom Körper)